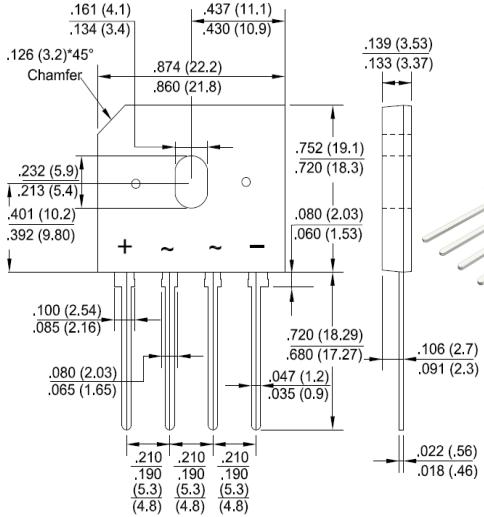


# GBU15005 THRU GBU1510

Glass Passivated Bridge Rectifiers	Reverse Voltage - 50 to 1000 Volts Forward Current - 15 Amperes
<p><b>Features</b></p> <ul style="list-style-type: none"> <li>● Glass passivated chip</li> <li>● Low forward voltage drop</li> <li>● Ideal for printed circuit board</li> <li>● High surge current capability</li> </ul> <p><b>Mechanical Data</b></p> <ul style="list-style-type: none"> <li>● Polarity: Symbol marked on body</li> <li>● Mounting position: Any</li> </ul> <p><b>Applications</b></p> <ul style="list-style-type: none"> <li>● General purpose use in AC/DC bridge full wave rectification, for SMPS, lighting ballaster, adapter, etc.</li> </ul>	   <p>Package Outline Dimensions in Inches (Millimeters)</p>

## Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristics	Symbol	GBU 15005	GBU 1501	GBU 1502	GBU 1504	GBU 1506	GBU 1508	GBU 1510	Unit
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current (with heatsink Note 2)	I <sub>(AV)</sub>	15.0 3.2							A
Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	240							A
I <sup>2</sup> t Rating for Fusing (t<8.3mS)	I <sup>2</sup> t	239							A <sup>2</sup> s
Peak Forward Voltage per Diode at 7.5A DC	V <sub>F</sub>	1.0							V
Maximum DC Reverse Current @T <sub>J</sub> =25°C	I <sub>R</sub>	5.0							μA
DC Blocking Voltage per Diode @T <sub>J</sub> =125°C		500							
Typical Junction Capacitance per Diode (Note1)	C <sub>J</sub>	70							pF
Typical Thermal Resistance to Ambient (Note2)	R <sub>θJA</sub>	8							
Typical Thermal Resistance to case (Note2)	R <sub>θJC</sub>	2							°C/W
Typical Thermal Resistance to lead (Note2)	R <sub>θJL</sub>	1.5							
Operating Junction Temperature Range	T <sub>J</sub>	-55 to +150							°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150							°C

Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

2. Device mounted on 100mm\*100mm\*1.6mm Cu plate heatsink.

3. The typical data above is for reference only

# Rating and Characteristic Curves

## GBU15005 THRU GBU1510

Fig. 1 - Forward Current Derating Curve

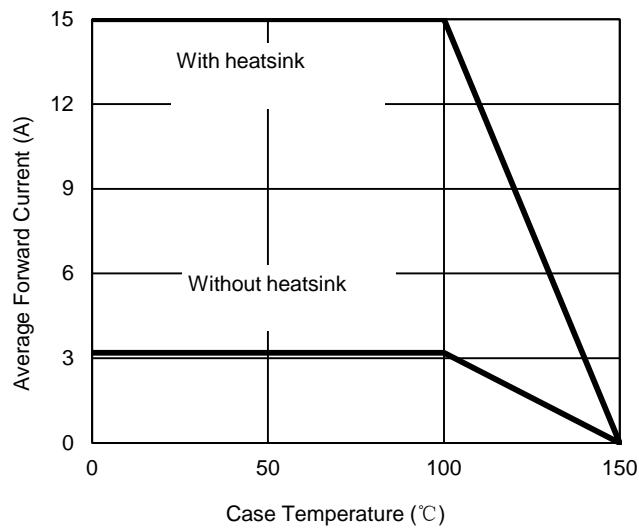


Fig. 2 - Maximum Non-Repetitive Surge Current

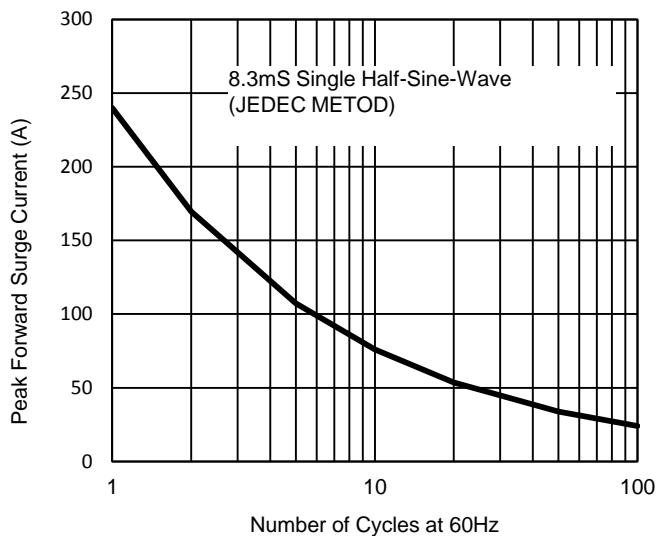


Fig. 3 - Typical Reverse Characteristics

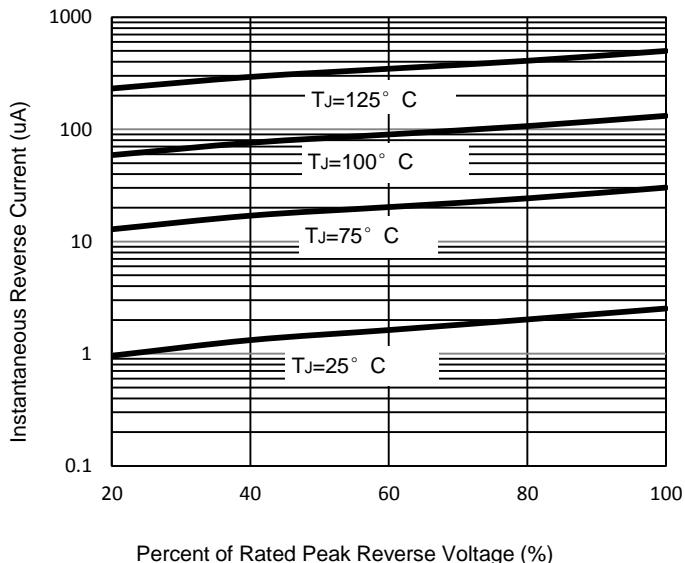
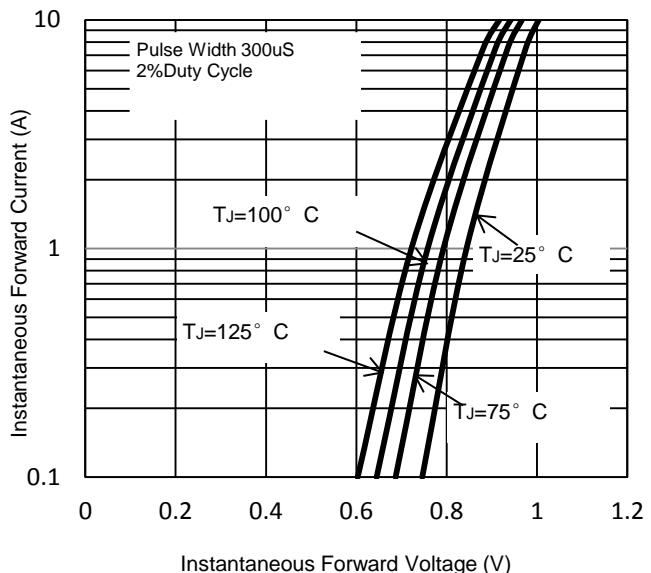


Fig. 4 - Typical Forward Characteristics



The curve above is for reference only.

GBU15\*-U/B-00/99-00/01  
Rev. 9, 22-Apr-2019